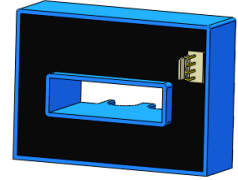




## Hall effect Open-loop current sensor SEH4 series



### Product description

#### Features

- Based on Hall effect measurement principle, open loop circuit mode.
- The isolation voltage between primary and secondary is greater than 3000VAC.
- Comply with UL94-V0 flame retardant rating.

#### Performance

- Can measure DC, AC, pulse, and various irregular waveforms under isolated conditions.
- Wide measurement range, fast response speed, low zero drift, low temperature drift, high accuracy and good linearity.
- Dynamic performance (di/dt and response time) is optimal when the busbar is fully filled with primary perforations.
- Strong ability to resist external electromagnetic interference (BCI, EFT, CS, CE, ESD, dv/dt, etc.).

#### Application:

- It can be widely used in inverters, UPS, photovoltaic inverters, electric vehicle drives, high-frequency power supplies, inverter welding machines and other products.

#### Implementation standards

- GB/T 7665-2005
- JB/T 7490-2007
- JB/T 25480-2010
- JB/T 9473-2020
- SJ 20792-2000

#### Certification



## Technical Parameters

Model Parameters (25°C)	SEH4							
	300A	400A	500A	600A	800A	1000A	1500A	2000A
Primary Current $I_{PN}$	300A	400A	500A	600A	800A	1000A	1500A	2000A
Primary Current Max. Peak Value $I_{PM}$	±900A	±1200A	±1500A	±1800A	±2400A	±3000A	±3500A	±3500A
Output voltage $V_{out}$ @ $\pm I_{PN}$ , $R_L=10K\Omega$	±4V±1%							

## Electrical Data

Item	Min.	Typical	Max.	Unit
Input power supply voltage range $V_c$ (±5%) (Remark 1, Remark 2)	±11	±15	±18	$V_{DC}$
Current consumption $I_c$	-	±15	±20	mA
Withstand resistance $R_{INS}$ @500V DC	1000	-	-	$M\Omega$
Output voltage $V_{out}$ @ $I_{PN}$ , $R_L=10K\Omega$ , $T_A=25^\circ C$	3.960	4.000	4.040	V
Output internal resistance $R_{OUT}$	-	102	-	$\Omega$
Load Resistance $R_L$ (Remark 3)	1	10	-	$K\Omega$
Accuracy $X$ @ $I_{PN}$ , $T_A=25^\circ C$	-	±1	-	%
Linearity $\epsilon_L$ @ $R_L=10K\Omega$ , $T_A=25^\circ C$	-	±0.5	-	% $I_{PN}$
Offset voltage $V_{OE}$ @ $T_A=25^\circ C$	-	±10	±20	mV
Hysteresis voltage $V_{OM}$ @ $I_{PN} \rightarrow 0$	-	±10	±20	mV
Temperature Coefficient of Offset Voltage $TCV_{OE}$	-	±0.5	±1	mV/°C
Output voltage temperature coefficient $TCV_{out}$	-	±0.05	±0.1	%/°C
Response time $t_D$ @ $0 \rightarrow I_{PN}$	-	3	5	us
Ambient operating temperature $T_A$	-40	25	125	°C
Ambient storage temperature $T_s$	-40	25	125	°C
Withstand voltage $V_D$ @ 50Hz, 60s, 0.1mA		3000		$V_{AC}$
Weight m		210		g

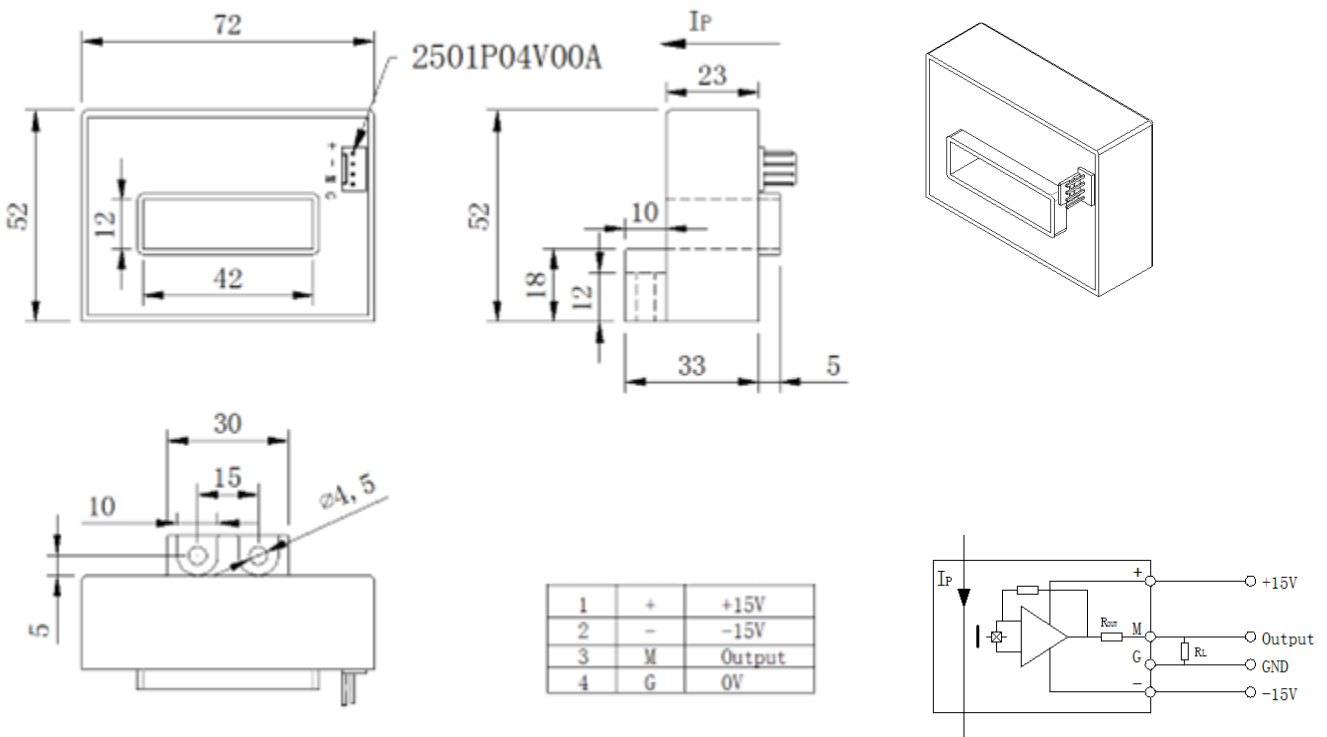
Remarks:

1. If VC is less than the minimum value, the measurement will be inaccurate. If VC is greater than the maximum value, it may cause permanent failure of the measuring device.
2. When  $\pm 12V < VCC < \pm 15V$ , will reduce the measurement range.

$$3. V_{OUT} = 4.04 * \frac{R_L}{102 + R_L} * \frac{I_P}{I_{PN}} + V_{OE}$$

4.  $di/dt > 50A/\mu S$

### Dimensions (in mm)



Notes:

1. Size error:  $\pm 1mm$ ;
2. Primary aperture:  $41.6*12mm$ ;
3. Fastening hole:  $\phi 4.5mm*2$ ;
4. SEH4 output terminal: 2501P04V00A;
5. The IP indication direction is the positive direction of the current;
6. The temperature of the primary conductor shall not exceed  $105^{\circ}C$ ;
7. Incorrect wiring may cause damage to the sensor.